



PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Ideally Suited for Automatic Insertion
- Complementary NPN Types: BC846 BC848
- · For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotive-products/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

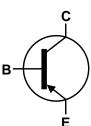
Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)

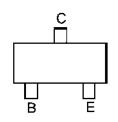
SOT23







Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

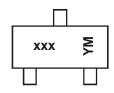
Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC856A-7-F	AEC-Q101	K3A	7	3,000
BC856B-7-F	AEC-Q101	K3B	7	3,000
BC856B-13-F	AEC-Q101	K3B	13	10,000
BC857A-7-F	AEC-Q101	K3A	7	3,000
BC857B-7-F	AEC-Q101	K3B	7	3,000
BC857B-13-F	AEC-Q101	K3B	13	10,000

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC857C-7-F	AEC-Q101	K3G	7	3,000
BC857C-13-F	AEC-Q101	K3G	13	10,000
BC858A-7-F	AEC-Q101	K3A	7	3,000
BC858B-7-F	AEC-Q101	K3B	7	3,000
BC858C-7-F	AEC-Q101	K3G	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



xxx = Product Type Marking Code (Please see Ordering Information)

YM = Date Code Marking Y or \overline{Y} = Year (ex: G = 2019)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2019		2020	2021		2022	2023		2024	2025		2026
Code	G		Н			J	K		L	M		N
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteris	stic	Symbol	Value	Unit
	BC856		-80	
Collector-Base Voltage	BC857	Vсво	-50	V
_	BC858	1	-30	
	BC856		-65	
Collector-Emitter Voltage	BC857	VCEO	-45	V
	BC858]	-30	
Emitter-Base Voltage		V _{EBO}	-5.0	V
Continuous Collector Current		Ic	-100	mA
Peak Collector Current		Ісм	-200	mA
Peak Emitter Current		ІЕМ	-200	mA
Peak Base Current		Івм	-200	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	D-	310	
Power Dissipation	(Note 6)	P _D	350	mW
Thermal Pesistance Junction to Ambient	(Note 5)	Davi	403	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	RθJA	357	*C/VV
Thermal Resistance, Junction to Leads (Note 7)		Rejl	350	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150	°C	

ESD Ratings (Note 8)

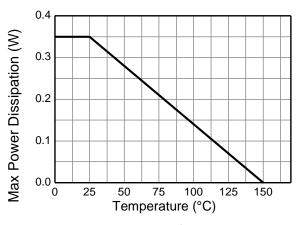
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

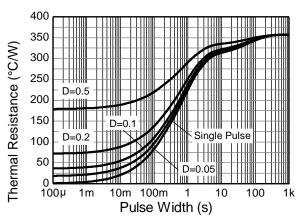
Notes:

- 5. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 15mm × 15mm 1oz copper.
 7. Thermal resistance from junction to solder-point (at the end of the leads).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



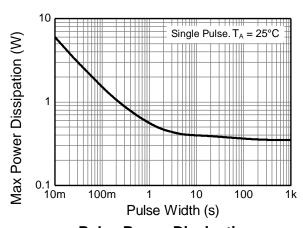
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Ch	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC856		-80					
Collector-Base Breakdown V	'oltage	BC857	ВУсво	-50	_	_	V	$I_C = -10\mu A$	
		BC858		-30					
Collector-Emitter Breakdown	Voltago	BC856		-65					
(Note 9)	voltage	BC857	BV _{CEO}	-45	_	_	V	$I_C = -10mA$	
(14010-0)		BC858		-30					
Emitter-Base Breakdown Vo	ltage		BV _{EBO}	-5	_	_	V	I _E = -1μA	
Collector Cutoff Current			Ісво	_		-15	nA	V _{CB} = -30V	
Concolor Caton Carrent			ICBO			-4	μΑ	$V_{CB} = -30V, T_J = +150^{\circ}C$	
		BC856				-15		Vce = -80V	
Collector Emitter Cutoff Curre	ent	BC857	ICES		_	-15	nA	Vce = -50V	
		BC858				-15		Vce = -30V	
Emitter-Base Cutoff Current			IEBO	_	_	-100	nA	V _{EB} = -5V	
	BC856A / B	C857A / BC858A	1250		200				
Small Signal Current Gain	BC856B / B	C857B / BC858B	h _{fe}	_	330	_	_		
9		BC857C / BC858C			600				
	BC856A / E	C857A / BC858A			2.7			7	
Input Impedance	BC856B / BC857B / BC858B		h _{ie} –	_	4.5	_	kΩ	I _C = -2.0mA, V _{CE} = -5V f = 1.0kHz	
	BC857C / BC858C				8.7				
Output Admittance	BC856A / BC857A / BC858A BC856B / BC857B / BC858B		h _{oe}	_	18				
Output Admittance					30	_	μS		
		'C / BC858C			60				
Reverse Voltage Transfer	BC856A / BC857A / BC858A BC856B / BC857B / BC858B BC857C / BC858C			_	1.5x10 ⁻⁴	_	_		
Ratio			h _{re}		2x10 ⁻⁴				
					3x10 ⁻⁴				
		C857A / BC858A		125	180	250			
DC Current Gain (Note 9)	BC856B / BC857B / BC858B		hFE	220	290	475	_	$I_C = -2.0 \text{mA}, V_{CE} = -5 \text{V}$	
	BC857	C / BC858C		420	520	800			
Collector-Emitter Saturation	Voltage (Note 9)		VcE(sat)	_	-75	-300	mV	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$	
			· OL(Gat)		-250	-650		$I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$	
Base-Emitter Turn-On Voltag	re (Note 9)		V _{BE(on)}	-600	-650	-750	mV	$I_C = -2mA$, $V_{CE} = -5V$	
Base Emilier Turn On Voltag	ge (Note 3)		v BE(on)	1	_	-820	111 V	$I_C = -10 \text{mA}$, $V_{CE} = -5 \text{V}$	
Base-Emitter Saturation Voltage (Note 9)		V		-700	1	mV	$I_C = -10 \text{mA}, I_B = -0.5 \text{mA}$		
		V _{BE(sat)}		-850	-1100		$I_C = -100 \text{mA}, I_B = -5 \text{mA}$		
Output Capacitance			Cobo	_	3	_	pF	V _{CB} = -10V, f = 1.0MHz	
Transition Frequency			fT	100	200	_	MHz	V _{CE} = -5V, I _C = -10mA, f = 100MHz	
Noise Figure			NF	_	2	10	dB	$V_{CE} = -5V, \ I_{C} = -200\mu A$ $R_{S} = 2k\Omega, \ f = 1kHz$ $\Delta f = 200Hz$	

Note:

9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (BC856B) (@TA = +25°C, unless otherwise specified.)

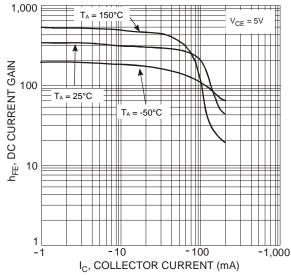


Figure 1 Typical DC Current Gain vs. Collector Current

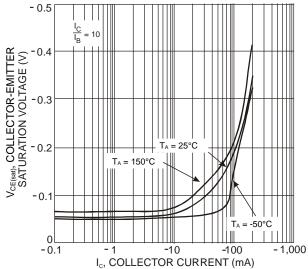


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current

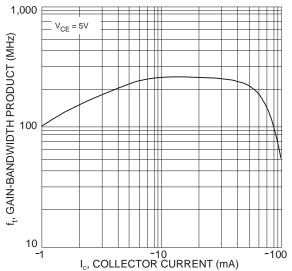


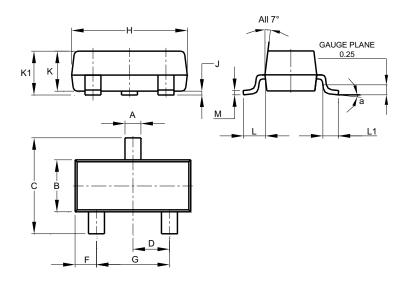
Figure 3 Gain-Bandwidth Product vs Collector Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

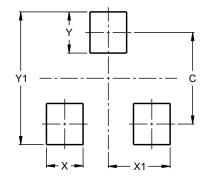


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°					
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Y	0.9
Y1	2.9



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